



Date : 19.07.2018

**Attention all applicants for the post of Executive Trainee- 23<sup>rd</sup> Batch through GATE-2018**

Further to the detailed advertisement dated Advt. No. CC/04/2017 dated 04.09.2017, notification 01/2018 dated 05.01.2018 and declaration of results of GATE-2018, Interview and Group Discussions for the post of Executive Trainee 23<sup>rd</sup> batch in Electrical, Electronics and Civil disciplines are scheduled to be held from last week of July 2018 onwards.

The discipline-wise cutoff marks (GATE marks out of 100) for being shortlisted for GD & Interviews at this stage is as follows:

**Post – ET (Electrical), GATE Paper – EE**

Category	Cut off marks
UR	72.67
OBC (NCL)	65.00
SC	54.33
ST	56.67
PwD-OH	32.67
PwD-HH	26.00

**Post – ET (Electronics), GATE Paper – EC**

Category	Cut off marks
UR	63.00
OBC (NCL)	57.67

**Post – ET (Civil), GATE Paper – CE**

Category	Cut off marks
UR	85.65
OBC (NCL)	78.84
SC	76.22
ST	74.25

Candidates are shortlisted provisionally\*on the basis of their normalized marks out of 100 in the corresponding papers of GATE 2018 and are being issued call letters through their CANDIDATE LOGIN. Shortlisted candidates are advised to follow the instructions as mentioned in their candidate login accounts and their respective call letters.

\* Subject to their being found eligible as per our notification dated 04.09.2017